

**ISO120**  
**ISO121**

## Precision Low Cost ISOLATION AMPLIFIER

### FEATURES

- 100% TESTED FOR PARTIAL DISCHARGE
- ISO120: Rated 1500Vrms
- ISO121: Rated 3500Vrms
- HIGH IMR: 115dB at 60Hz
- USER CONTROL OF CARRIER FREQUENCY
- LOW NONLINEARITY:  $\pm 0.01\%$  max
- BIPOLAR OPERATION:  $V_o = \pm 10V$
- 0.3"-WIDE 24-PIN HERMETIC DIP, ISO120
- SYNCHRONIZATION CAPABILITY
- WIDE TEMP RANGE:  $-55^\circ C$  to  $+125^\circ C$  (ISO120)

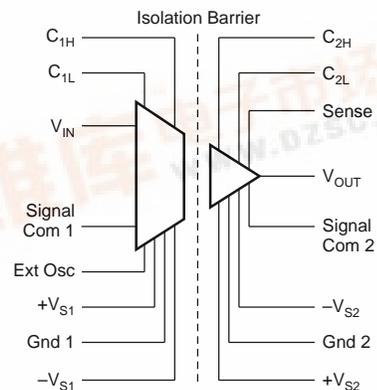
### APPLICATIONS

- INDUSTRIAL PROCESS CONTROL: Transducer Isolator for Thermocouples, RTDs, Pressure Bridges, and Flow Meters, 4mA to 20mA Loop Isolation
- GROUND LOOP ELIMINATION
- MOTOR AND SCR CONTROL
- POWER MONITORING
- ANALYTICAL MEASUREMENTS
- BIOMEDICAL MEASUREMENTS
- DATA ACQUISITION
- TEST EQUIPMENT

### DESCRIPTION

The ISO120 and ISO121 are precision isolation amplifiers incorporating a novel duty cycle modulation-demodulation technique. The signal is transmitted digitally across a 2pF differential capacitive barrier. With digital modulation the barrier characteristics do not affect signal integrity, which results in excellent reliability and good high frequency transient immunity across the barrier. Both the amplifier and barrier capacitors are housed in a hermetic DIP. The ISO120 and ISO121 differ only in package size and isolation voltage rating.

These amplifiers are easy to use. No external components are required for 60kHz bandwidth. With the addition of two external capacitors, precision specifications of 0.01% max nonlinearity and  $150\mu V/^\circ C$  max  $V_{OS}$  drift are guaranteed with 6kHz bandwidth. A power supply range of  $\pm 4.5V$  to  $\pm 18V$  and low quiescent current make these amplifiers ideal for a wide range of applications.



# SPECIFICATIONS

## ELECTRICAL

At  $T_A = +25^\circ\text{C}$ :  $V_{S1} = V_{S2} = \pm 15\text{V}$ ; and  $R_L = 2\text{k}\Omega$ , unless otherwise noted.

PARAMETER	CONDITIONS	ISO120BG, ISO121BG			ISO120G, ISO120SG <sup>(4)</sup> , ISO121G			UNITS
		MIN	TYP	MAX	MIN	TYP	MAX	
<b>ISOLATION</b>								
Voltage Rated Continuous ISO120: AC 60Hz	$T_{\text{MIN}}$ to $T_{\text{MAX}}$	1500			*			Vrms
DC	$T_{\text{MIN}}$ to $T_{\text{MAX}}$	2121			*			VDC
ISO121: AC 60Hz	$T_{\text{MIN}}$ to $T_{\text{MAX}}$	3500			*			Vrms
DC	$T_{\text{MIN}}$ to $T_{\text{MAX}}$	4950			*			VDC
100% Test (AC 60Hz): ISO120	1s; Partial Discharge $\leq 5\text{pC}$	2500			*			Vrms
ISO121	1s; Partial Discharge $\leq 5\text{pC}$	5600			*			Vrms
Isolation Mode Rejection ISO 120: AC 60Hz	1500Vrms		115			*		dB
DC			160			*		dB
ISO121: AC60Hz	3500Vrms		115			*		dB
DC			160			*		dB
Barrier Impedance			$10^{14} \parallel 2$			*		$\Omega \parallel \text{pF}$
Leakage Current	$V_{\text{ISO}} = 240\text{Vrms}, 60\text{Hz}$		0.18	0.5		*	*	$\mu\text{Arms}$
<b>GAIN<sup>(4)</sup></b>								
Nominal Gain	$V_O = \pm 10\text{V}$ $C_1 = C_2 = 1000\text{pF}$		1			1		V/V
Gain Error			$\pm 0.04$	$\pm 0.1$		$\pm 0.05$	$\pm 0.25$	%FSR
Gain vs Temperature			$\pm 5$	$\pm 20$		$\pm 10$	$\pm 40$	ppm/ $^\circ\text{C}$
Nonlinearity			$\pm 0.005$	$\pm 0.01$		$\pm 0.01$	$\pm 0.05$	%FSR
Nominal Gain	$C_1 = C_2 = 0$		1			1		V/V
Gain Error			$\pm 0.04$	$\pm 0.25$		$\pm 0.05$	$\pm 0.25$	%FSR
Gain vs Temperature			$\pm 40$			$\pm 40$		ppm/ $^\circ\text{C}$
Nonlinearity			$\pm 0.02$	$\pm 0.1$		$\pm 0.04$	$\pm 0.1$	%FSR
<b>INPUT OFFSET VOLTAGE<sup>(4)</sup></b>								
Initial Offset vs Temperature	$C_1 = C_2 = 1000\text{pF}$		$\pm 5$	$\pm 25$		$\pm 10$	$\pm 50$	mV
Initial Offset vs Temperature	$C_1 = C_2 = 0$		$\pm 100$	$\pm 150$		$\pm 150$	$\pm 400$	$\mu\text{V}/^\circ\text{C}$
Initial Offset vs Supply	$\pm V_{S1}$ or $\pm V_{S2} = \pm 4.5\text{V}$ to $\pm 18\text{V}$		$\pm 2$			$\pm 2$		$\text{mV}/\text{V}$
Noise			4			4		$\mu\text{V}/\sqrt{\text{Hz}}$
<b>INPUT</b>								
Voltage Range <sup>(1)</sup>		$\pm 10$	$\pm 15$		*	*		V
Resistance			200			*		$\text{k}\Omega$
<b>OUTPUT</b>								
Voltage Range		$\pm 10$	$\pm 12.5$		*	*		V
Current Drive		$\pm 5$	$\pm 15$		*	*		mA
Capacitive Load Drive			0.1			*		$\mu\text{F}$
Ripple Voltage <sup>(2)</sup>			10			*		mVp-p
<b>FREQUENCY RESPONSE</b>								
Small Signal Bandwidth	$C_1 = C_2 = 0$		60			*		kHz
	$C_1 = C_2 = 1000\text{pF}$		6			*		kHz
Slew Rate			2			*		V/ $\mu\text{s}$
Settling Time	$V_O = \pm 10\text{V}$							
0.1%	$C_2 = 100\text{pF}$		50			*		$\mu\text{s}$
0.01%	$C_1 = C_2 = 1000\text{pF}$		350			*		$\mu\text{s}$
Overload Recovery Time <sup>(3)</sup>	50% Output Overload, $C_1 = C_2 = 0$		150			*		$\mu\text{s}$
<b>POWER SUPPLIES</b>								
Rated Voltage			15			*		V
Voltage Range		$\pm 4.5$		$\pm 18$	*		*	V
Quiescent Current: $V_{S1}$			$\pm 4.0$	$\pm 5.5$		*	*	mA
$V_{S2}$			$\pm 5.0$	$\pm 6.5$		*	*	mA
<b>TEMPERATURE RANGE</b>								
Specification: BG and G		-25		85	-25		85	$^\circ\text{C}$
SG <sup>(4)</sup>		-25		85	-55		125	$^\circ\text{C}$
Operating		-55		125	-55		125	$^\circ\text{C}$
Storage		-65		150	-55		150	$^\circ\text{C}$
$\theta_{JA}$ : ISO120			40			40		$^\circ\text{C}/\text{W}$
ISO121			25			25		$^\circ\text{C}/\text{W}$

\*Specifications same as ISO120BG, ISO121BG.

NOTE: (1) Input voltage range =  $\pm 10\text{V}$  for  $V_{S1}, V_{S2} = \pm 4.5\text{VDC}$  to  $\pm 18\text{VDC}$ . (2) Ripple frequency is at carrier frequency. (3) Overload recovery is approximately three times the settling time for other values of  $C_2$ . (4) The SG-grade is specified  $-55^\circ\text{C}$  to  $+125^\circ\text{C}$ ; performance of the SG in the  $-25^\circ\text{C}$  to  $+85^\circ\text{C}$  temperature range is the same as the BG-grade.

## ABSOLUTE MAXIMUM RATINGS

Supply Voltage (any supply)	18V
$V_{IN}$ Sense Voltage	$\pm 100V$
External Oscillator Input	$\pm 25V$
Signal Common 1 to Ground 1	$\pm 1V$
Signal Common 2 to Ground 2	$\pm 1V$
Continuous Isolation Voltage: ISO120	1500Vrms
ISO121	3500Vrms
$V_{ISO1}$ dv/dt	20kV/ $\mu s$
Junction Temperature	150°C
Storage Temperature	-65°C to +150°C
Lead Temperature (soldering, 10s)	+300°C
Output Short Duration	Continuous to Common

## PACKAGE INFORMATION<sup>(1)</sup>

MODEL	PACKAGE	PACKAGE DRAWING NUMBER
ISO120G	24-Pin DIP	225
ISO120BG	24-Pin DIP	225
ISO120SG	24-Pin DIP	225
ISO121G	40-Pin DIP	206
ISO121BG	40-Pin DIP	206

NOTE: (1) For detailed drawing and dimension table, please see end of data sheet, or Appendix D of Burr-Brown IC Data Book.

## ORDERING INFORMATION

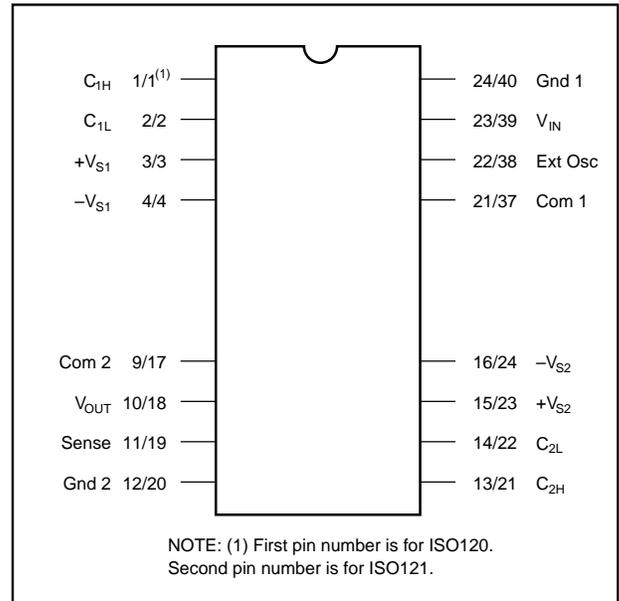
MODEL	TEMPERATURE RANGE
ISO120G	-25°C to 85°C
ISO120BG	-25°C to 85°C
ISO120SG	-55°C to 125°C
ISO121G	-25°C to 85°C
ISO121BG	-25°C to 85°C



## ELECTROSTATIC DISCHARGE SENSITIVITY

Electrostatic discharge can cause damage ranging from performance degradation to complete device failure. Burr-Brown Corporation recommends that all integrated circuits be handled and stored using appropriate ESD protection methods.

## CONNECTION DIAGRAM

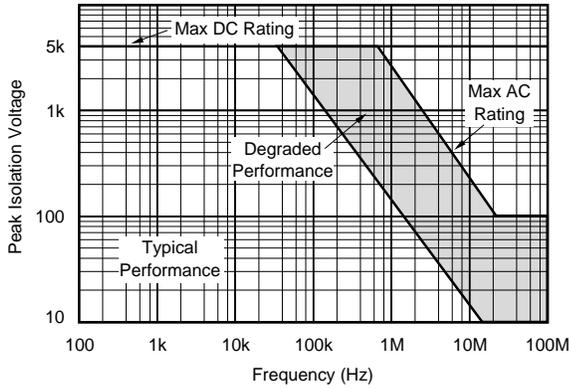


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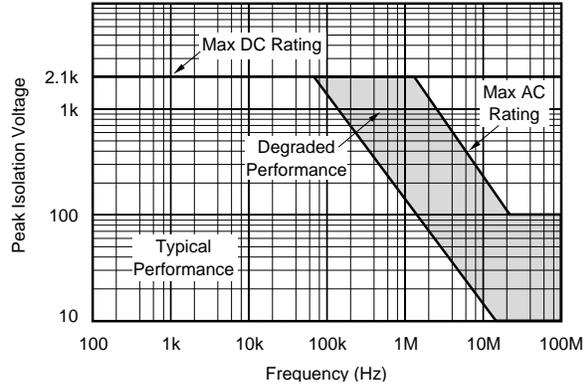
# TYPICAL PERFORMANCE CURVES

$T_A = +25^\circ\text{C}$ ;  $V_{S1} = V_{S2} = \pm 15\text{V}$ ; and  $R_L = 2\text{k}\Omega$ , unless otherwise noted.

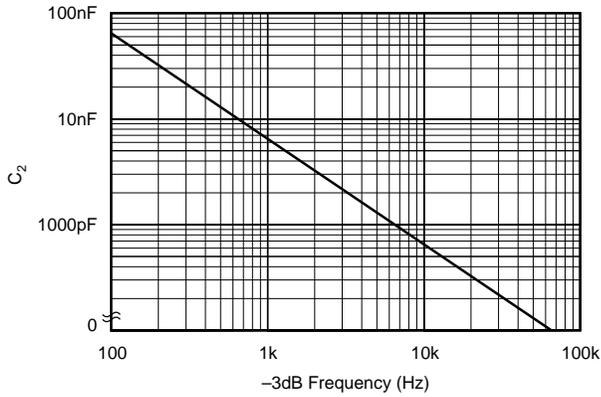
ISOLATION MODE VOLTAGE vs FREQUENCY ISO121



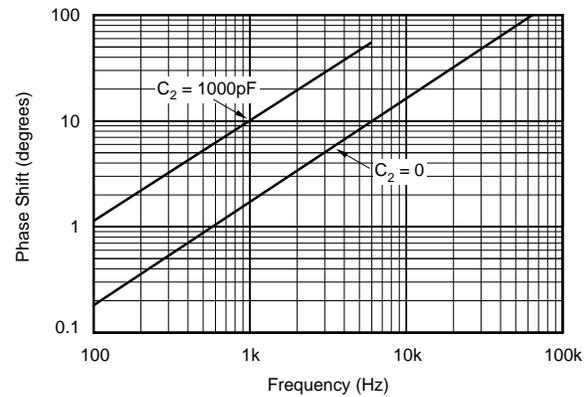
ISOLATION MODE VOLTAGE vs FREQUENCY ISO120



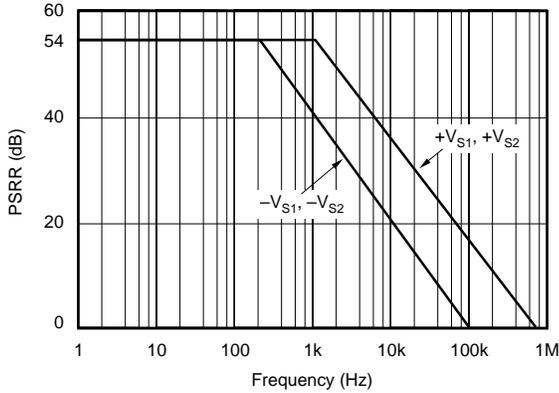
BANDWIDTH vs  $C_2$



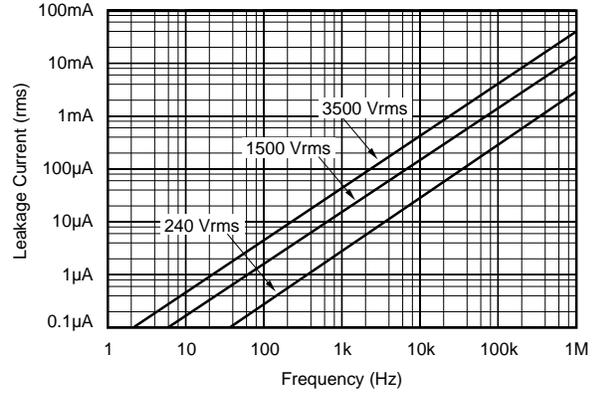
PHASE SHIFT vs  $C_2$



PSRR vs FREQUENCY

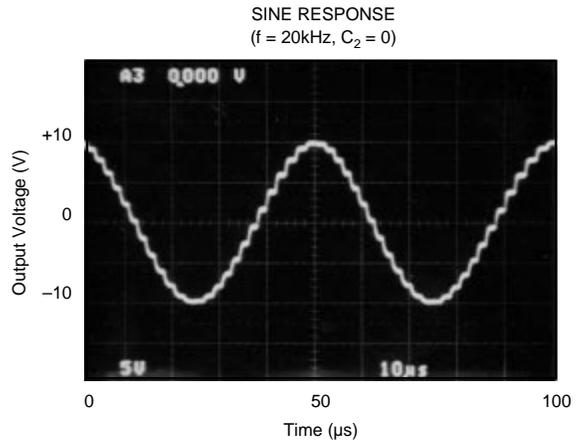
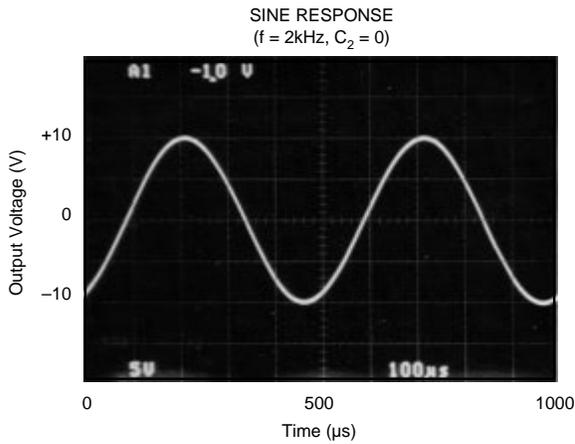
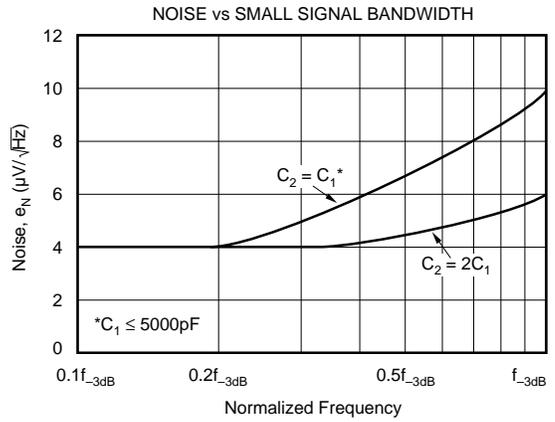
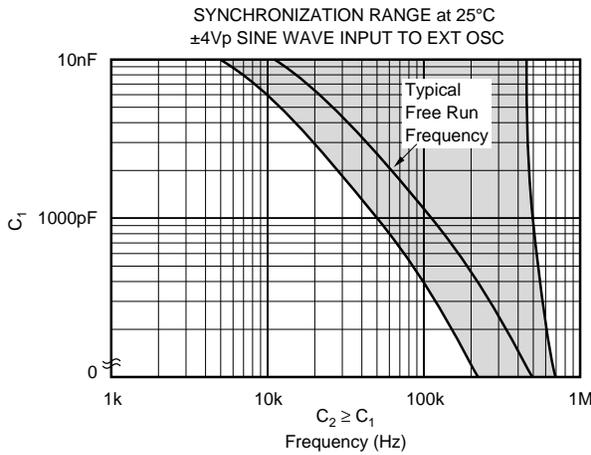
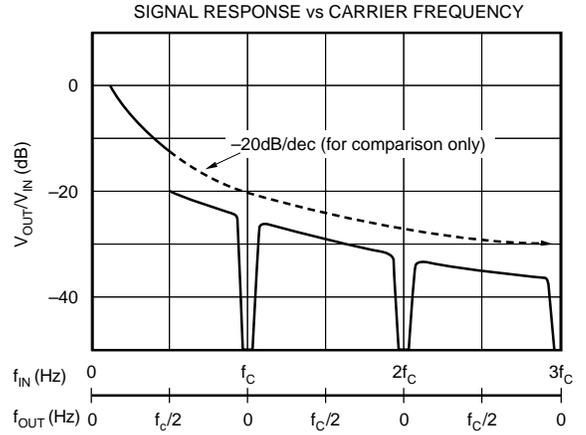
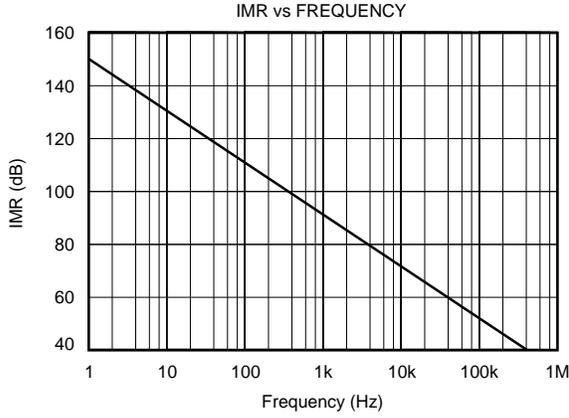


ISOLATION LEAKAGE CURRENT vs FREQUENCY



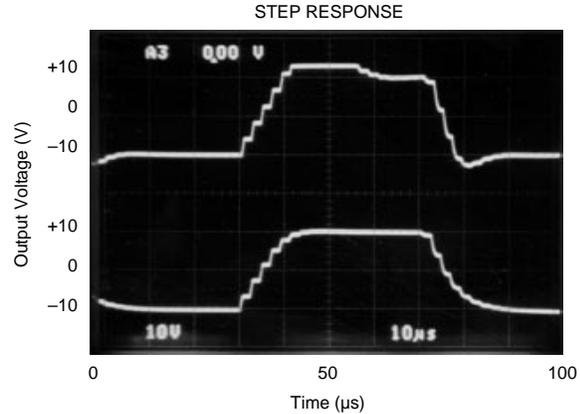
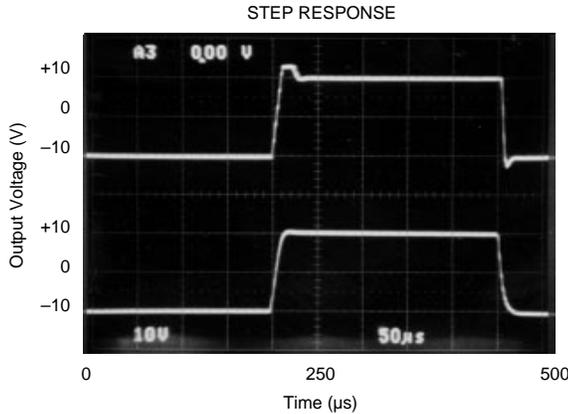
# TYPICAL PERFORMANCE CURVES (CONT)

$T_A = +25^\circ\text{C}$ ;  $V_{S1} = V_{S2} = \pm 15\text{V}$ ; and  $R_L = 2\text{k}\Omega$ , unless otherwise noted.



## TYPICAL PERFORMANCE CURVES (CONT)

$T_A = +25^\circ\text{C}$ ;  $V_{S1} = V_{S2} = \pm 15\text{V}$ ; and  $R_L = 2\text{k}\Omega$ , unless otherwise noted.



## THEORY OF OPERATION

The ISO120 and ISO121 isolation amplifiers comprise input and output sections galvanically isolated by matched 1pF capacitors built into the ceramic barrier. The input is duty-cycle modulated and transmitted digitally across the barrier. The output section receives the modulated signal, converts it back to an analog voltage and removes the ripple component inherent in the demodulation. The input and output sections are laser-trimmed for exceptional matching of circuitry common to both input and output sections.

### FREE-RUNNING MODE

An input amplifier (A1, Figure 1) integrates the difference between the input current ( $V_{IN}/200\text{k}\Omega$ ) and a switched  $\pm 100\mu\text{A}$  current source. This current source is implemented by a switchable  $200\mu\text{A}$  source and a fixed  $100\mu\text{A}$  current sink. To understand the basic operation of the input section, assume that  $V_{IN} = 0$ . The integrator will ramp in one direction until the comparator threshold is exceeded. The comparator and sense amp will force the current source to switch; the resultant signal is a triangular waveform with a 50% duty cycle. If  $V_{IN}$  changes, the duty cycle of the integrator will change to keep the average DC value at the output of A1 near zero volts. This action converts the input voltage to a duty-cycle modulated triangular waveform at the output of A1 near zero volts. This action converts the input voltage to a duty-cycle modulated triangular waveform at the output of A1 with a frequency determined by the internal 150pF capacitor. The comparator generates a fast rise time square wave that is simultaneously fed back to keep A1 in charge balance and also across the barrier to a differential sense amplifier with high common-mode rejection characteristics. The sense amplifier drives a switched current source surrounding A2. The output stage balances the duty-cycle modulated current against the feedback current through the  $200\text{k}\Omega$  feedback resistor, resulting in an average value at the Sense pin equal to  $V_{IN}$ . The sample and hold amplifiers in the output feedback loop serve to remove undesired ripple voltages inherent in the demodulation process.

### SYNCHRONIZED MODE

A unique feature of the ISO120 and ISO121 is the ability to synchronize the modulator to an external signal source. This capability is useful in eliminating trouble-some beat frequencies in multi-channel systems and in rejecting AC signals and their harmonics. To use this feature, external capacitors are connected at  $C_1$  and  $C_2$  (Figure 1) to change the free-running carrier frequency. An external signal is applied to the Ext Osc pin. This signal forces the current source to switch at the frequency of the external signal. If  $V_{IN}$  is zero, and the external source has a 50% duty cycle, operation proceeds as described above, except that the switching frequency is that of the external source. If the external signal has a duty cycle other than 50%, its average value is not zero. At start-up, the current source does not switch until the integrator establishes an output equal to the average DC value of the external signal. At this point, the external signal is able to trigger the current source, producing a triangular waveform, symmetrical about the new DC value, at the output of A1. For  $V_{IN} = 0$ , this waveform has a 50% duty cycle. As  $V_{IN}$  varies, the waveform retains its DC offset, but varies in duty cycle to maintain charge balance around A1. Operation of the demodulator is the same as outlined above.

### Synchronizing to a Sine or Triangle Wave External Clock

The ideal external clock signal for the ISO120/121 is a  $\pm 4\text{V}$  sine wave or  $\pm 4\text{V}$ , 50% duty-cycle triangle wave. The *ext osc* pin of the ISO120/121 can be driven directly with a  $\pm 3\text{V}$  to  $\pm 5\text{V}$  sine or 25% to 75% duty-cycle triangle wave and the ISO amp's internal modulator/demodulator circuitry will synchronize to the signal.

Synchronizing to signals below 400kHz requires the addition of two external capacitors to the ISO120/121. Connect one capacitor in parallel with the internal modulator capacitor and connect the other capacitor in parallel with the internal demodulator capacitor as shown in Figure 1.

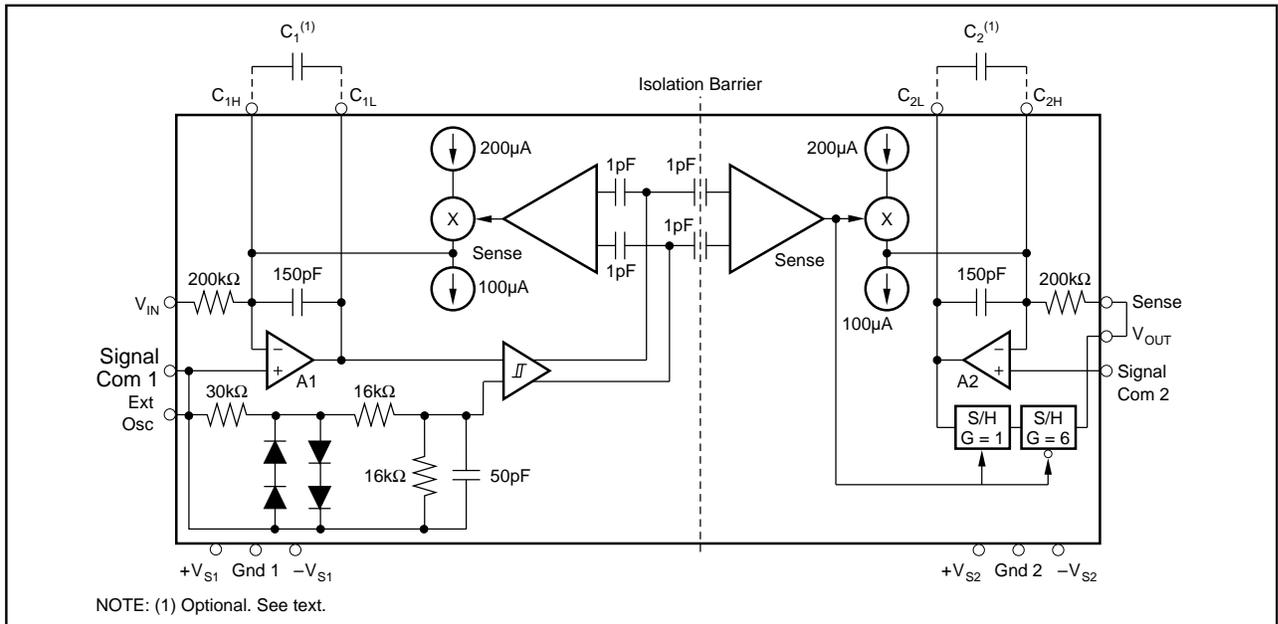


FIGURE 1. Block Diagram.

The value of the external modulator capacitor,  $C_1$ , depends on the frequency of the external clock signal. Table I lists recommended values.

EXTERNAL CLOCK FREQUENCY RANGE	$C_1, C_2$ ISO120/121 MODULATOR, DEMODULATOR EXTERNAL CAPACITOR
400kHz to 700kHz	none
200kHz to 400kHz	500pF
100kHz to 200kHz	1000pF
50kHz to 100kHz	2200pF
20kHz to 50kHz	4700pF
10kHz to 20kHz	0.01μF
5kHz to 10kHz	0.022μF

TABLE I. Recommended ISO120/121 External Modulator/Demodulator Capacitor Values vs External Clock Frequency.

The value of the external demodulator capacitor,  $C_2$ , depends on the value of the external modulator capacitor. To assure stability,  $C_2$  must be greater than  $0.8 \cdot C_1$ . A larger value for  $C_2$  will decrease bandwidth and improve stability:

$$f_{-3\text{dB}} \approx \frac{1.2}{200\text{k}\Omega (150\text{pF} + C_2)}$$

Where:

$f_{-3\text{dB}} \approx -3\text{dB}$  bandwidth of ISO amp with external  $C_2$  (Hz)  
 $C_2$  = External demodulator capacitor (f)

For example, with  $C_2 = 0.01\mu\text{F}$ , the  $f_{-3\text{dB}}$  bandwidth of the ISO120/121 is approximately 600Hz.

### Synchronizing to a 400kHz to 700kHz Square-Wave External Clock

At frequencies above 400kHz, an internal clamp and filter provides signal conditioning so that a square-wave signal can be used to directly drive the ISO120/121. A square-wave external clock signal can be used to directly drive the ISO120/121 *ext osc* pin if: the signal is in the 400kHz to 700kHz frequency range with a 25% to 75% duty cycle, and  $\pm 3\text{V}$  to  $\pm 20\text{V}$  level. Details of the internal clamp and filter circuitry are shown in Figure 1.

### Synchronizing to a 10% to 90% Duty-cycle External Clock

With the addition of the signal conditioning circuit shown in Figure 2, any 10% to 90% duty-cycle square-wave signal can be used to drive the ISO120/121 *ext osc* pin. With the values shown, the circuit can be driven by a 4Vp-p TTL signal. For a higher or lower voltage input, increase or decrease the 1kΩ resistor,  $R_x$ , proportionally. e.g. for a  $\pm 4\text{V}$  square wave (8Vp-p)  $R_x$  should be increased to 2kΩ.

The value of  $C_x$  used in the Figure 2 circuit depends on the frequency of the external clock signal. Table II shows recommended capacitor values.

Note: For external clock frequencies below 400kHz, external modulator/demodulator capacitors are required on the ISO120/121 as before.

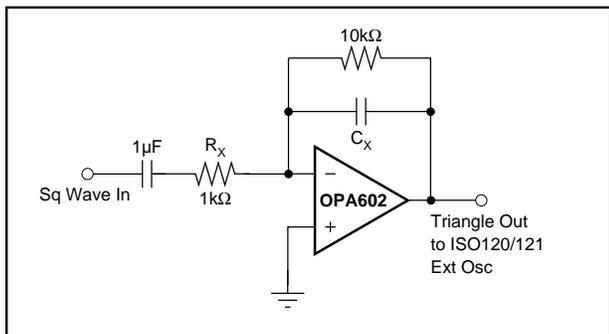


FIGURE 2. Square Wave to Triangle Wave Signal Conditioner for Driving ISO120/121 Ext Osc Pin.

EXTERNAL CLOCK FREQUENCY RANGE	$C_x$
400kHz to 700kHz	30pF
200kHz to 400kHz	180pF
100kHz to 200kHz	680pF
50kHz to 100kHz	1800pF
20kHz to 50kHz	3300pF
10kHz to 20kHz	0.01µF
5kHz to 10kHz	0.022µF

TABLE II. Recommended  $C_x$  Values vs Frequency for Figure 2 Circuit.

## BASIC OPERATION

### Signal and Power Connections

Figure 3 shows proper power and signal connections. Each power supply pin should be bypassed with 1µF tantalum capacitor located as close to the amplifier as possible. All ground connections should be run independently to a common point if possible. Signal Common on both input and output sections provide a high-impedance point for sensing signal ground in noisy applications. Signal Common must have a path to ground for bias current return and should be maintained within ±1V of Gnd. The output sense pin may be

connected directly to  $V_{OUT}$  or may be connected to a remote load to eliminate errors due to IR drops. Pins are provided for use of external integrator capacitors. The  $C_{1H}$  and  $C_{2H}$  pins are connected to the integrator summing junctions and are therefore particularly sensitive to external pickup. This sensitivity will most often appear as degraded IMR or PSR performance. AC or DC currents coupled into these pins results in  $V_{ERROR} = I_{ERROR} \times 200k\Omega$  at the output. Guarding of these pins to their respective Signal Common, or  $C_{1L}$  and  $C_{2L}$  is strongly recommended. For similar reasons, long traces or physically large capacitors are not desirable. If wound-foil capacitors are used, the outside foil should be connected to  $C_{1L}$  and  $C_{2L}$ , respectively.

### Optional Gain and Offset Adjustments

Rated gain accuracy and offset performance can be achieved with no external adjustments, but the circuit of Figure 4a may be used to provide a gain trim of ±0.5% for values shown; greater range may be provided by increasing the size of  $R_1$  and  $R_2$ . Every 2kΩ increase in  $R_1$  will give an additional 1% adjustment range, with  $R_2 \geq 2R_1$ . If safety or convenience dictates location of the adjustment potentiometer on the other side of the barrier from the position shown in Figure 4a, the positions of  $R_1$  and  $R_2$  may be reversed. Gains greater than one may be obtained by using the circuit of Figure 4b. Note that the effect of input offset errors will be multiplied at the output in proportion to the increase in gain. Also, the small-signal bandwidth will be decreased in inverse proportion to the increase in gain. In most instances, a precision gain block at the input of the isolation amplifier will provide better overall performance.

Figure 5 shows a method for trimming  $V_{OS}$  of the ISO120 and ISO121. This circuit may be applied to either Signal Com (input or output) as desired for safety or convenience. With the values shown, ±15V supplies and unity gain, the circuit will provide ±150mV adjustment range and 0.25mV

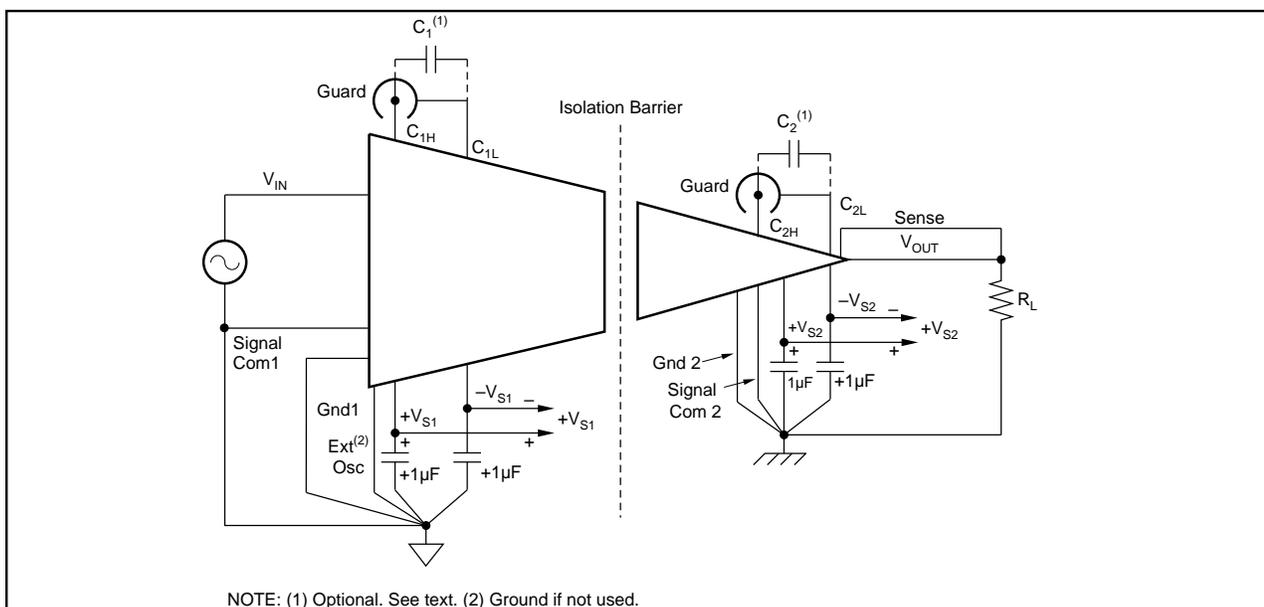


FIGURE 3. Power and Signal Connections.

resolution with a typical trim potentiometer. The output will have some sensitivity to power supply variations. For a  $\pm 100\text{mV}$  trim, power supply sensitivity is  $8\text{mV/V}$  at the output.

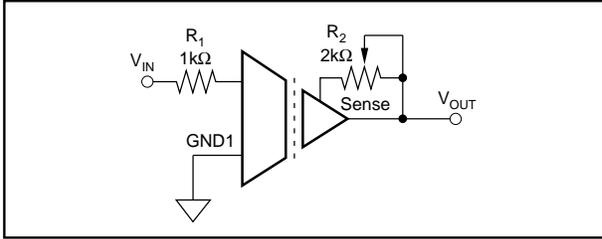


FIGURE 4a. Gain Adjust.

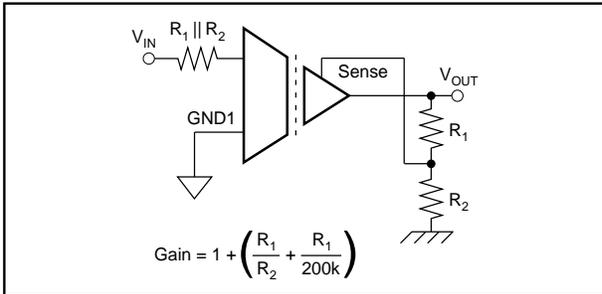


FIGURE 4b. Gain Setting.

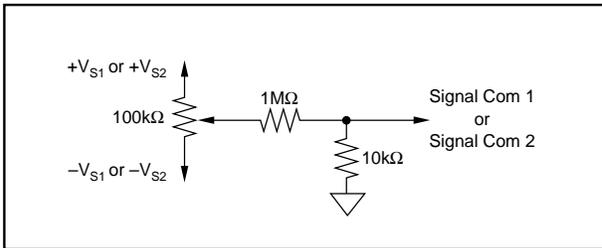


FIGURE 5.  $V_{OS}$  Adjust.

### CARRIER FREQUENCY CONSIDERATIONS

As previously discussed, the ISO120 and ISO121 amplifiers transmit the signal across the iso-barrier by a duty-cycle modulation technique. This system works like any linear amplifier for input signals having frequencies below one half the carrier frequency,  $f_c$ . For signal frequencies above  $f_c/2$ , the behavior becomes more complex. The Signal Response vs Carrier Frequency performance curve describes this behavior graphically. The upper curve illustrates the response for input signals varying from DC to  $f_c/2$ . At input frequencies at or above  $f_c/2$ , the device generates an output signal component that varies in both amplitude and frequency, as shown by the lower curve. The lower horizontal scale shows the periodic variation in the frequency of the output component. Note that at the carrier frequency and its harmonics, both the frequency and amplitude of the response go to zero. These characteristics can be exploited in certain applications. It should be noted that when  $C_1$  is zero, the carrier frequency is nominally  $500\text{kHz}$  and the  $-3\text{dB}$  point of the amplifier is  $60\text{kHz}$ . Spurious signals at the

output are not significant under these circumstances unless the input signal contains significant components above  $250\text{kHz}$ .

There are two ways to use these characteristics. One is to move the carrier frequency low enough that the troublesome signal components are attenuated to an acceptable level as shown in Signal Response vs Carrier Frequency. This in effect limits the bandwidth of the amplifier. The Synchronization Range performance curve shows the relationship between carrier frequency and the value of  $C_1$ . To maintain stability,  $C_2$  must also be connected and must be equal to or larger in value than  $C_1$ .  $C_2$  may be further increased in value for additional attenuation of the undesired signal components and provides the additional benefit of reducing the residual carrier ripple at the output. See the Bandwidth vs  $C_2$  performance curve.

When periodic noise from external sources such as system clocks and DC/DC converters are a problem, ISO120 and ISO121 can be used to reject this noise. The amplifier can be synchronized to an external frequency source,  $f_{EXT}$ , placing the amplifier response curve at one of the frequency and amplitude nulls indicated in the Signal Response vs Carrier Frequency performance curve. For proper synchronization, choose  $C_1$  as shown in the Synchronization Range performance curve. Remember that  $C_2 \geq C_1$  is a necessary condition for stability of the isolation amplifier. This curve shows the range of lock at the fundamental frequency for a  $4\text{V}$  sinusoidal signal source. The applications section shows the ISO120 and ISO121 synchronized to isolation power supplies, while Figure 6 shows circuitry with opto-isolation suitable for driving the Ext Osc input from TTL levels.

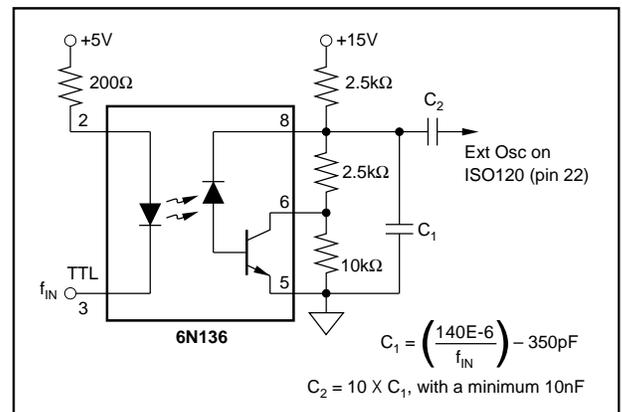


FIGURE 6. Synchronization with Isolated Drive Circuit for Ext Osc Pin.

### ISOLATION MODE VOLTAGE

Isolation mode voltage (IMV) is the voltage appearing between isolated grounds Gnd 1 and Gnd 2. IMV can induce error at the output as indicated by the plots of IMV vs Frequency. It should be noted that if the IMV frequency exceeds  $f_c/2$ , the output will display spurious outputs in a manner similar to that described above, and the amplifier response will be identical to that shown in the Signal Response vs Carrier Frequency performance curve. This occurs

because IMV-induced errors behave like input-referred error signals. To predict the total IMR, divide the isolation voltage by the IMR shown in IMR vs Frequency performance curve and compute the amplifier response to this input-referred error signal from the data given in the Signal Response vs Carrier Frequency performance curve. Due to effects of very high-frequency signals, typical IMV performance can be achieved only when  $dV/dT$  of the isolation mode voltage falls below  $1000V/\mu s$ . For convenience, this is plotted in the typical performance curves for the ISO120 and ISO121 as a function of voltage and frequency for sinusoidal voltages. When  $dV/dT$  exceeds  $1000V/\mu s$  but falls below  $20kV/\mu s$ , performance may be degraded. At rates of change above  $20kV/\mu s$ , the amplifier may be damaged, but the barrier retains its full integrity. Lowering the power supply voltages below  $\pm 15V$  may decrease the  $dV/dT$  to  $500V/\mu s$  for typical performance, but the maximum  $dV/dT$  of  $20kV/\mu s$  remains unchanged.

Leakage current is determined solely by the impedance of the  $2pF$  barrier capacitance and is plotted in the Isolation Leakage Current vs Frequency curve.

### ISOLATION VOLTAGE RATINGS

Because a long-term test is impractical in a manufacturing situation, the generally accepted practice is to perform a production test at a higher voltage for some shorter time. The relationship between actual test voltage and the continuous derated maximum specification is an important one. Historically, Burr-Brown has chosen a deliberately conservative one:  $V_{TEST} = (2 \times ACrms \text{ continuous rating}) + 1000V$  for 10 seconds, followed by a test at rated ACrms voltage for one minute. This choice was appropriate for conditions where system transients are not well defined.

Recent improvements in high-voltage stress testing have produced a more meaningful test for determining maximum permissible voltage ratings, and Burr-Brown has chosen to apply this new technology in the manufacture and testing of the ISO120 and ISO121.

### Partial Discharge

When an insulation defect such as a void occurs within an insulation system, the defect will display localized corona or ionization during exposure to high-voltage stress. This ionization requires a higher applied voltage to start the discharge and lower voltage to maintain it or extinguish it once started. The higher start voltage is known as the inception voltage, while the extinction voltage is that level of voltage stress at which the discharge ceases. Just as the total insulation system has an inception voltage, so do the individual voids. A voltage will build up across a void until its inception voltage is reached, at which point the void will ionize,

effectively shorting itself out. This action redistributes electrical charge within the dielectric and is known as partial discharge. If, as is the case with AC, the applied voltage gradient across the device continues to rise, another partial discharge cycle begins. The importance of this phenomenon is that, if the discharge does not occur, the insulation system retains its integrity. If the discharge begins, and is allowed to continue, the action of the ions and electrons within the defect will eventually degrade any organic insulation system in which they occur. The measurement of partial discharge is still useful in rating the devices and providing quality control of the manufacturing process. Since the ISO120 and ISO121 do not use organic insulation, partial discharge is non-destructive.

The inception voltage for these voids tends to be constant, so that the measurement of *total charge* being redistributed within the dielectric is a very good indicator of the size of the voids and *their likelihood of becoming an incipient failure*. The *bulk inception voltage*, on the other hand, varies with the insulation system, and the number of ionization defects and directly establishes the *absolute maximum voltage* (transient) that can be applied across the test device before destructive partial discharge can begin. Measuring the *bulk extinction voltage* provides a lower, more conservative voltage from which to derive a *safe continuous rating*. In production, measuring at a level somewhat below the expected inception voltage and then derating by a factor related to expectations about system transients is an accepted practice.

### Partial Discharge Testing

Not only does this test method provide far more qualitative information about stress-withstand levels than did previous stress tests, but it provides quantitative measurements from which quality assurance and control measures can be based. Tests similar to this test have been used by some manufacturers, such as those of high-voltage power distribution equipment, for some time, but they employed a simple measurement of RF noise to detect ionization. This method was not quantitative with regard to energy of the discharge, and was not sensitive enough for small components such as isolation amplifiers. Now, however, manufacturers of HV test equipment have developed means to quantify partial discharge. VDE, the national standards group in Germany and an acknowledged leader in high-voltage test standards, has developed a standard test method to apply this powerful technique. Use of partial discharge testing is an improved method for measuring the integrity of an isolation barrier.

To accommodate poorly-defined transients, the part under test is exposed to voltage that is 1.6 times the continuous-rated voltage and must display  $\leq 5pC$  partial discharge level in a 100% production test.

# APPLICATIONS

The ISO120 and ISO121 isolation amplifiers are used in three categories of applications:

1. Accurate isolation of signals from high voltage ground potentials,

2. Accurate isolation of signals from severe ground noise and,
3. Fault protection from high voltages in analog measurements.

Figures 7 through 12 show a variety of Application Circuits.

# APPLICATION CIRCUITS

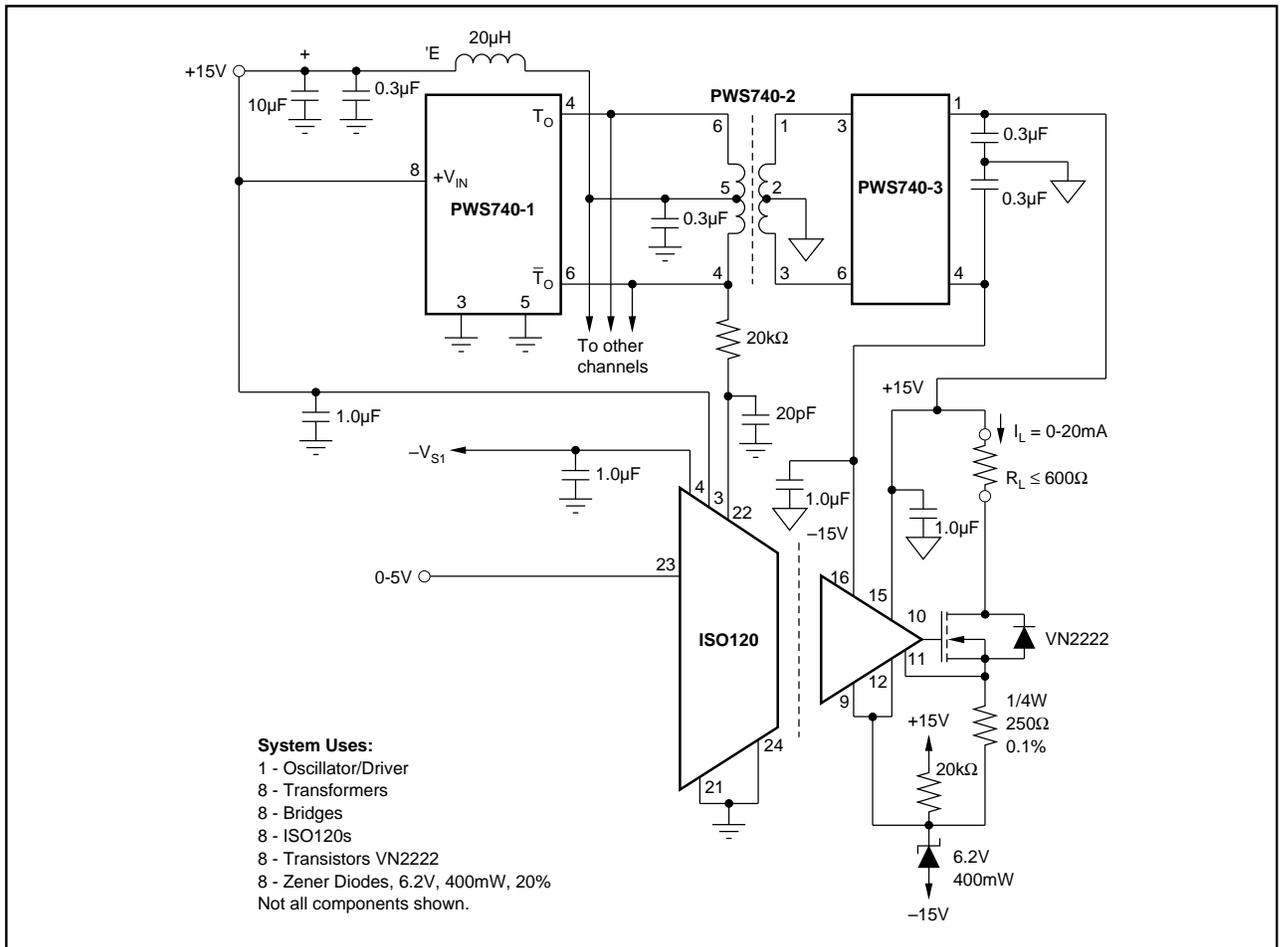


FIGURE 7. Eight-channel Isolated 0-20mA Loop Driver.

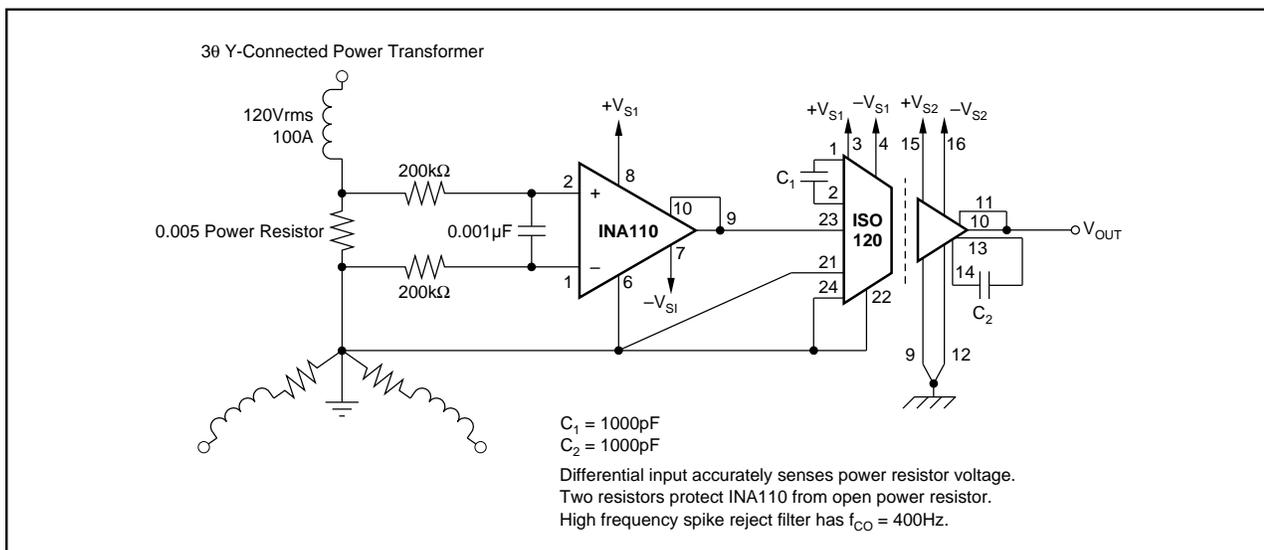


FIGURE 8. Isolated Powerline Monitor.

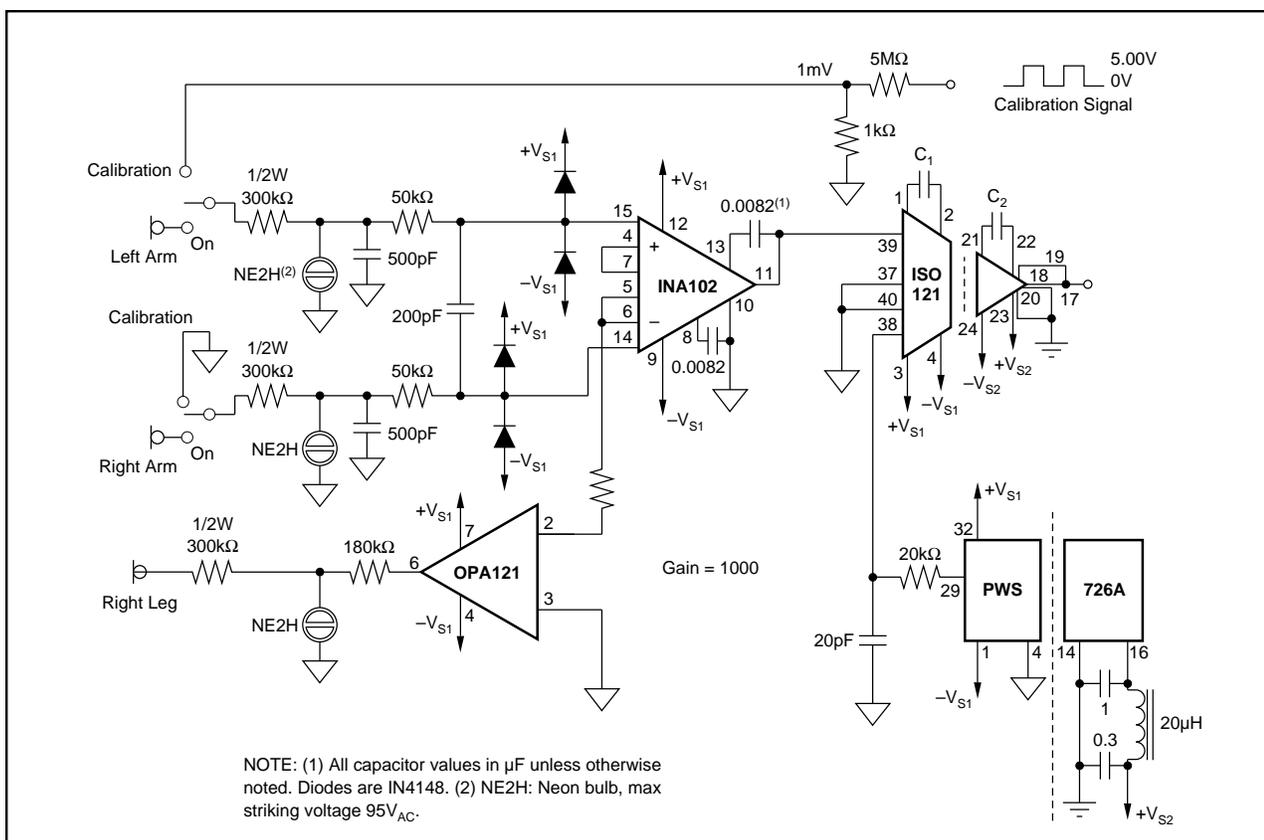


FIGURE 9. Right-Leg Driven ECG Amplifier (with defibrillator protection and calibration).

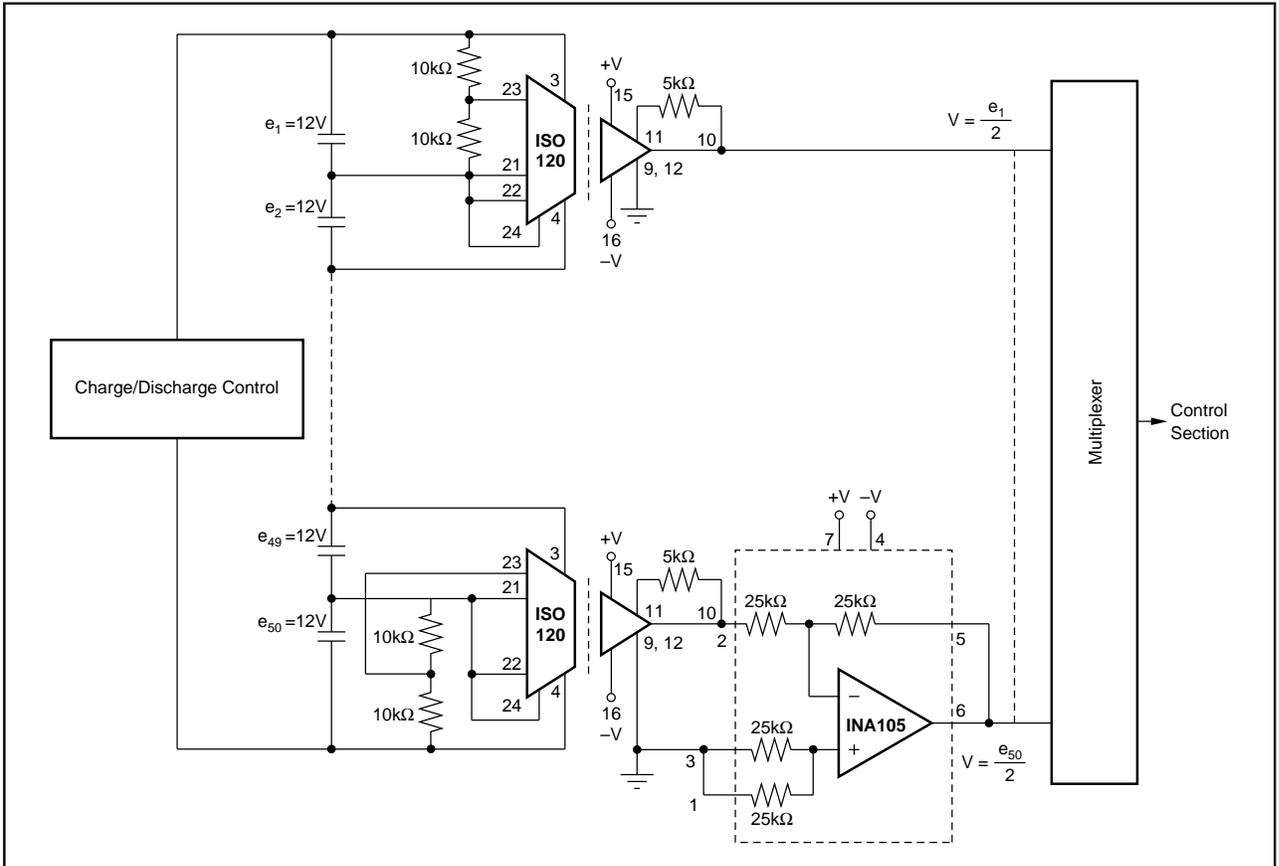


FIGURE 10. Battery Monitor for a 600V Battery Power System.

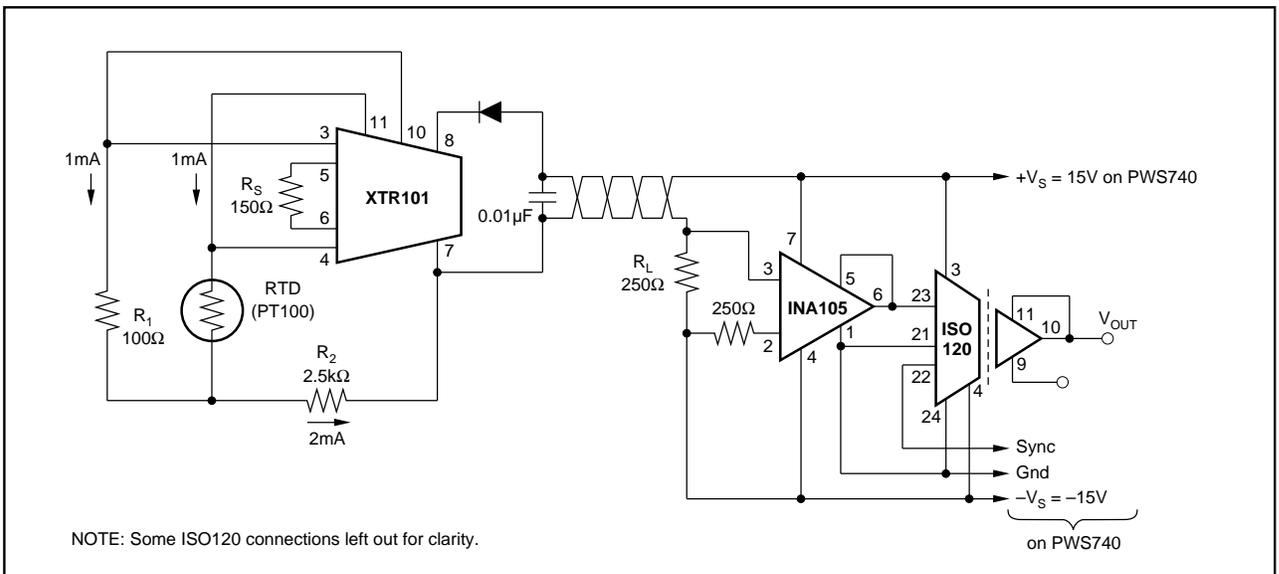


FIGURE 11. Isolated 4-20mA Instrument Loop. (RTD shown).

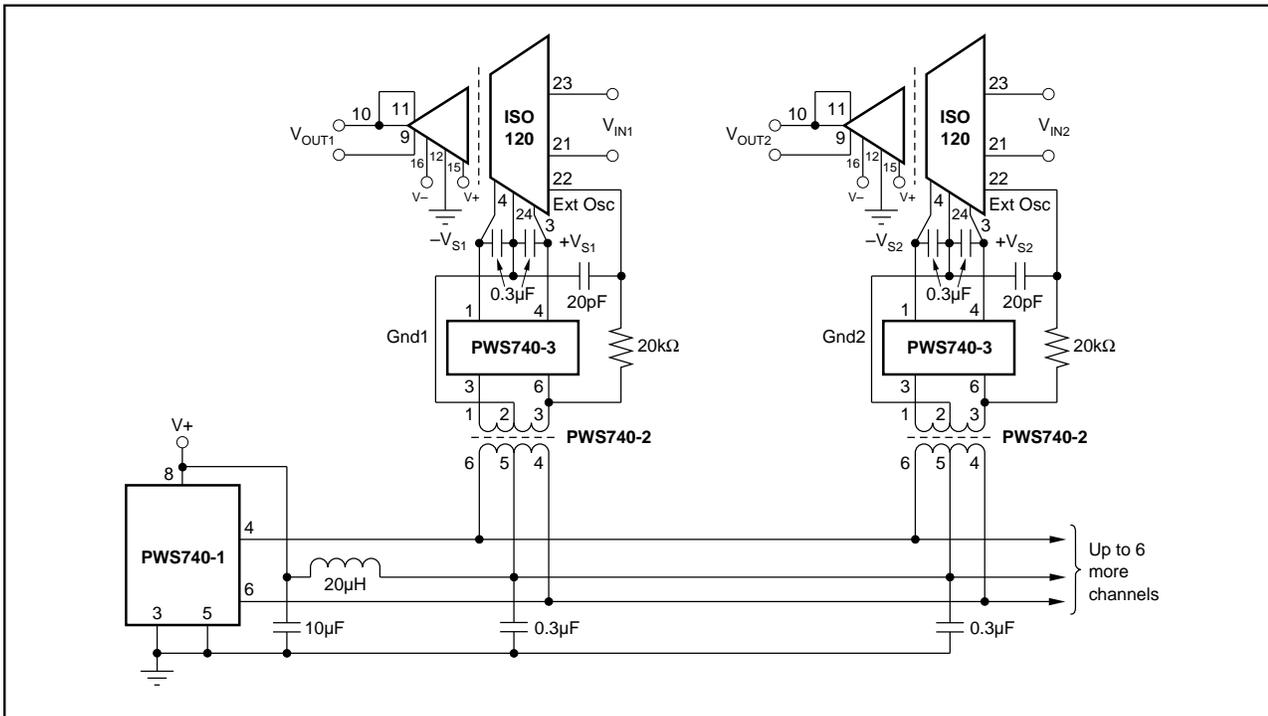


FIGURE 12. Synchronized-Multichannel Isolation System.

**PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
ISO120BG	NRND	CDIP SB	JVA	16	16	TBD	Call TI	Level-NA-NA-NA
ISO120G	NRND	CDIP SB	JVA	16	16	TBD	Call TI	Level-NA-NA-NA
ISO120SG	NRND	CDIP SB	JVA	16	16	TBD	Call TI	Level-NA-NA-NA
ISO120SGQ	OBSOLETE	CDIP SB	JVA	16		TBD	Call TI	Call TI
ISO121BG	NRND	CDIP SB	JVD	16	9	Green (RoHS & no Sb/Br)	Call TI	Level-NC-NC-NC
ISO121G	NRND	CDIP SB	JVD	16	9	Green (RoHS & no Sb/Br)	Call TI	Level-NC-NC-NC

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

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**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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